NSN 5961-01-045-8880

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View Online at https://aerobasegroup.com/nsn/5961-01-045-8880 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** Between 0.250 inches and 0.450 inches **Overall Width:** 1.050 inches **End Application:** E-3a **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open and 80.0 collector-to-emitter substaining voltage, resistance between base and emitter and 80.0 collector-to-emitter substaining voltage, with voltage between base and emitter **Current Rating Per Characteristic:** Between 120.00 milliamperes source cutoff current and 8.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 77630-642162 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life:

Vec - demil/mli

Unit Of Measure:

Demilitarization:

N/a

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